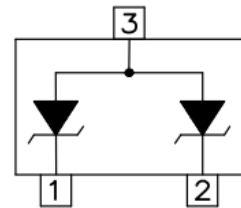


FEATURES

- Allows Either Two Separate Unidirectional Configurations or a Single Bidirectional Configurations.
- Low Leakage Current.
- 24-40 Watts Peak Power Protection.
- Excellent Clamping Capability.
- ESD Rating of Class N(exceeding 16KV)per the Human Body Model.
- Transient Voltage Suppressors Encapsulated in a SOT-23 Package.



Simplified outline(SOT-23)



MACHANICAL DATA

- Case: Molded Epoxy
- Marking: Marking Code
- Maximum Case Temperature for Soldering Purpose: 260 C for 10 sec.
- Weight: 0.008grams(approx.)

Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Value	Units
Peak Power Dissipation @ 1.0 ms @ $T_L \leq 25^\circ\text{C}$ ⁽¹⁾ MMBZ5V6ALT1G thru MMBZ10VALT1G MMBZ12VALT1G thru MMBZ33VALT1G	P_{PK}	24 40	W
Total Power Dissipation on FR-5 Board ⁽²⁾ @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Power Dissipation on Alumina Substrate ⁽³⁾ @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$
Lead Solder Temperature-Maximum(10 Second Duration)	T_L	260	$^\circ\text{C}$

NOTE: 1. Non-Repetitive Current Pulse, per FIG 5 and Derated above $T_A = 25^\circ\text{C}$ per FIG 6.

2. FR-5=1.0×0.75×0.62 in.

3. Alumina=0.4×0.3×0.024m, 99.5% alumina

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or Pins 2 and 3)

($V_F = 0.9\text{ V Max @ } I_F = 10\text{ mA}$)

24 WATTS

Device	Device Marking	V_{RWM} Volts	$I_R @ V_{RWM}$ uA	Breakdown Voltage				Max Zener Impedance ⁽⁵⁾			$V_C @ I_{PP}$ ⁽⁶⁾		θ_{VBR} mV/°C
				$V_{BR}^{(4)} (V)$			@ I_T	Z_{ZT} @ I_{ZT}	$Z_{ZK} @ I_{ZK}$		V_C	I_{PP}	
				Min	Nom	Max	mA	Ω	Ω	mA	V	A	
MMBZ5V6ALT1G	5A6	3.0	5.0	5.32	5.6	5.88	20	11	1600	0.25	8.0	3.0	1.26
MMBZ6V2ALT1G	6A2	3.0	0.5	5.89	6.2	6.51	1.0	-	-	-	8.7	2.76	2.80
MMBZ6V8ALT1G	6A8	4.5	0.5	6.46	6.8	7.14	1.0	-	-	-	9.6	2.5	3.4
MMBZ9V1ALT1G	9A1	6.0	0.3	8.65	9.1	9.56	1.0	-	-	-	14	1.7	7.5
MMBZ10VALT1G	10A	6.5	0.3	9.50	10	10.5	1.0	-	-	-	14.2	1.7	7.5

($V_F = 0.9\text{ V Max @ } I_F = 10\text{ mA}$)

40 WATTS

Device	Device Marking	V_{RWM} Volts	$I_R @ V_{RWM}$ nA	Breakdown Voltage				$V_C @ I_{PP}^{(6)}$		θ_{VBR} mV/°C
				$V_{BR}^{(4)} (V)$			@ I_T	V_C	I_{PP}	
				Min	Nom	Max	mA	V	A	
MMBZ12VALT1G	12A	8.5	200	11.40	12	12.60	1.0	17	2.35	7.5
MMBZ15VALT1G	15A	12	50	14.25	15	15.75	1.0	21	1.9	12.3
MMBZ18VALT1G	18A	14.5	50	17.10	18	18.90	1.0	25	1.6	15.3
MMBZ20VALT1G	20A	17	50	19.00	20	21.00	1.0	28	1.4	17.2
MMBZ27VALT1G	27A	22	50	25.65	27	28.35	1.0	40	1.0	24.3
MMBZ33VALT1G	33A	26	50	31.35	33	34.65	1.0	46	0.87	30.4

4. V_{BR} measured at pulse test current I_T at an ambient temperature of 25°C .

5. Z_{ZT} and Z_{ZK} are measured by dividing the AC voltage drop across the device by the AC current applied. The specified limits are for $I_{Z(AC)} = 0.1 I_{Z(DC)}$, with the AC frequency = 1.0 kHz.

6. Surge current waveform per Fig 5 and derate per Fig 6

Electrical Characteristics

($T_A = 25^\circ\text{C}$ unless otherwise noted)

UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or 2 and 3)

Symbol	Parameter
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
θV_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
V_{BR}	Maximum Temperature Coefficient of V_{BR}
I_F	Forward Current
V_F	Forward Voltage @ I_F
Z_{ZT}	Maximum Zener Impedance @ I_{ZT}
I_{ZK}	Reverse Current
Z_{ZK}	Maximum Zener Impedance @ I_{ZK}

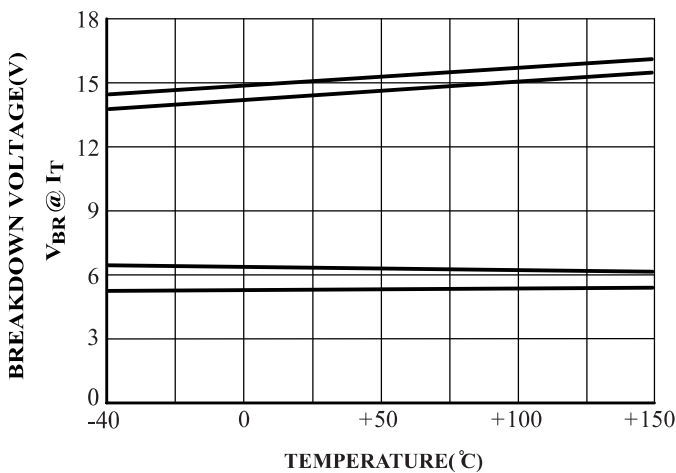
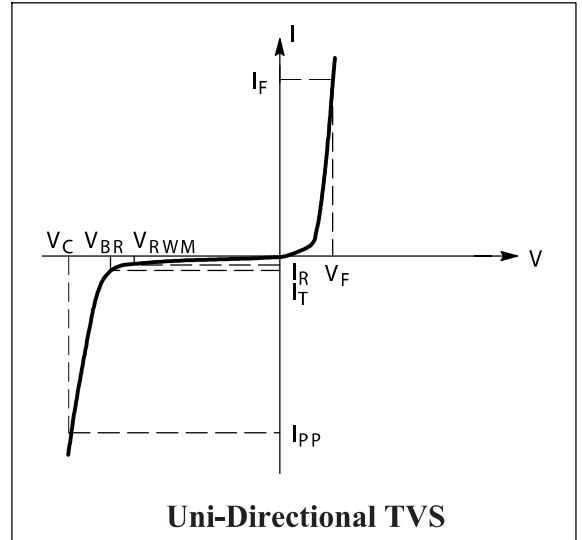


FIG.1 Typical Breakdown Voltage Versus Temperature

(Upper curve for each voltage is bidirectional mode,
lower curve is unidirectional mode)

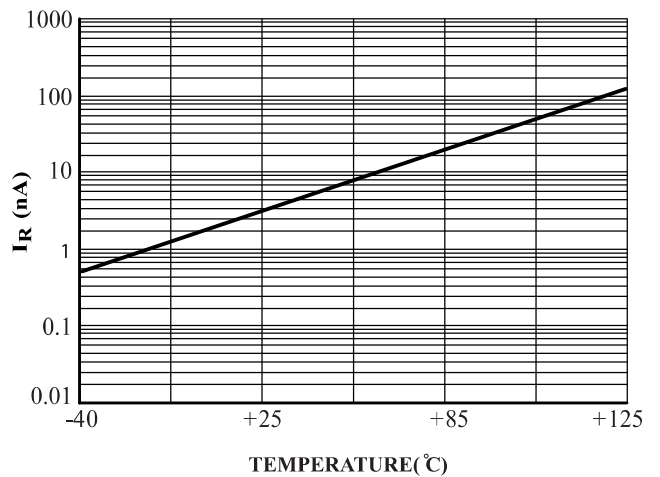


FIG.2 Typical Leakage Current Versus Temperature

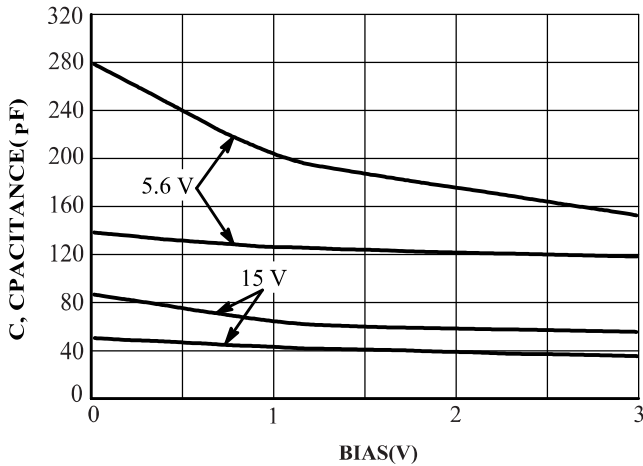


FIG.3 Typical Capacitance Versus Bias Voltage

(Upper curve for each voltage is bidirectional mode,) lower curve is unidirectional mode)

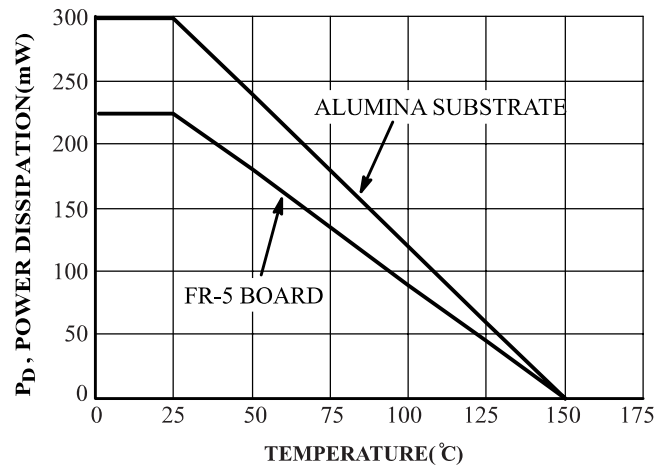


FIG.4 Steady State Power Derating Curve

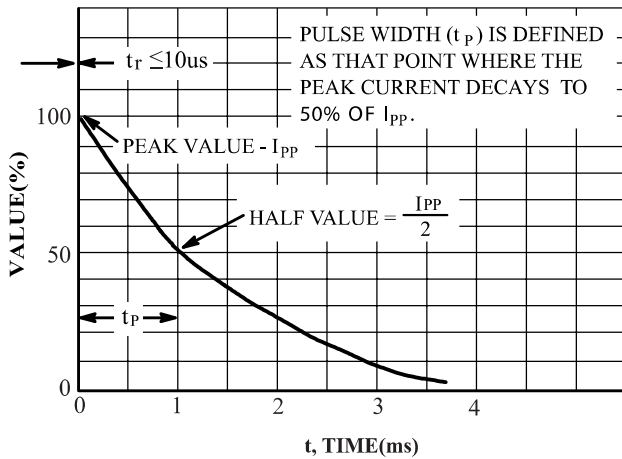


FIG.5 Pulse Waveform

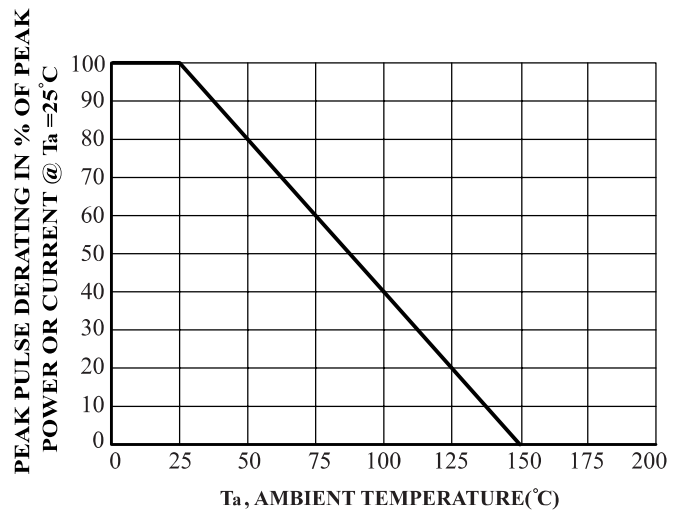


FIG.6 Pulse Derating Curve

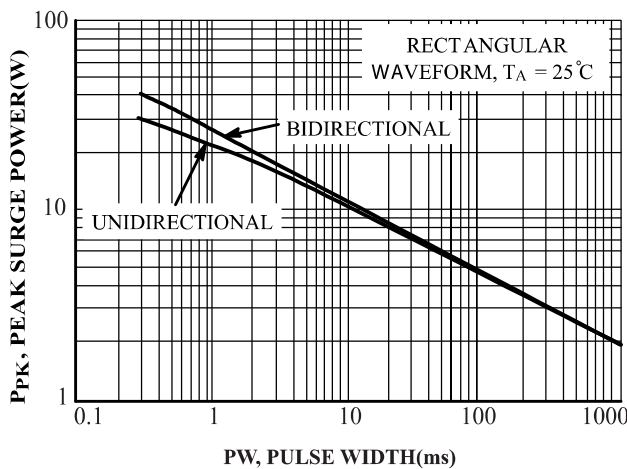


FIG.7 Maximum Non-repetitive Surge Power, P_{PK} Versus PW

Power is defined as $V_{RSM} \times I_Z(pk)$ where V_{RSM} is the clamping voltage at $I_Z(pk)$.

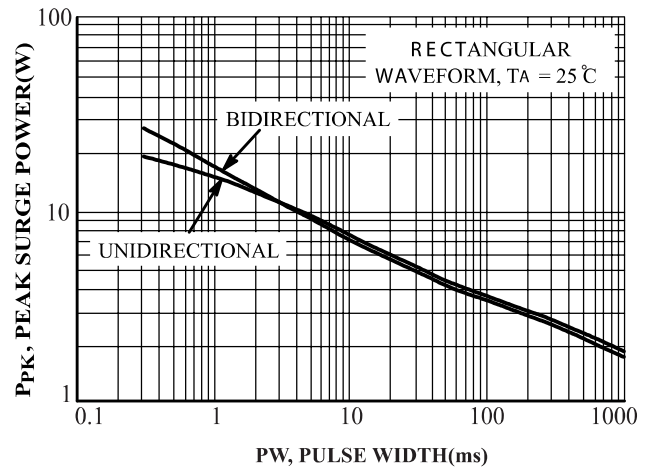
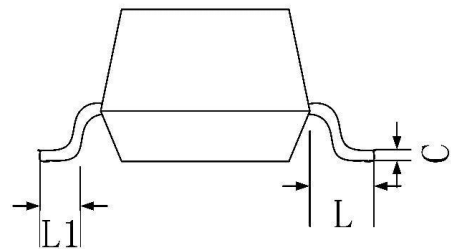
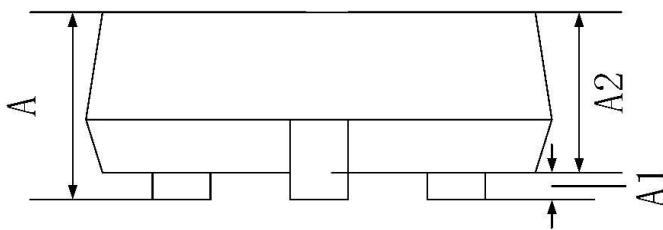
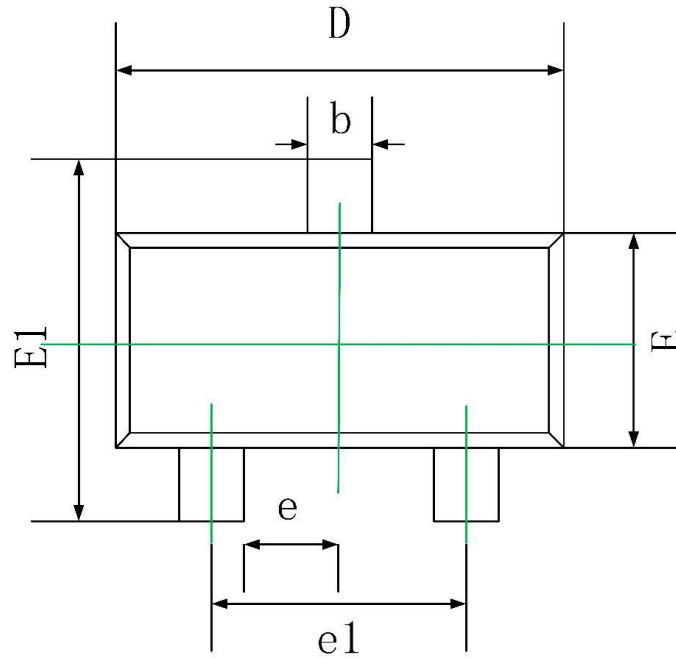


FIG.8 Maximum Non-repetitive Surge Power, $P_{PK}(NOM)$ Versus PW

Power is defined as $V_Z(NOM) \times I_Z(pk)$ where $V_Z(NOM)$ is the nominal Zener voltage measured at the low test current used for voltage classification

SOT-23 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020